

October 1987 Revised April 2002

## **CD4093BC**

# **Quad 2-Input NAND Schmitt Trigger**

### **General Description**

The CD4093B consists of four Schmitt-trigger circuits. Each circuit functions as a 2-input NAND gate with Schmitt-trigger action on both inputs. The gate switches at different points for positive and negative-going signals. The difference between the positive  $(V_T^+)$  and the negative voltage  $(V_T^-)$  is defined as hysteresis voltage  $(V_H)$ .

All outputs have equal source and sink currents and conform to standard B-series output drive (see Static Electrical Characteristics).

#### **Features**

- Wide supply voltage range: 3.0V to 15V
- Schmitt-trigger on each input with no external components
- Noise immunity greater than 50%
- Equal source and sink currents
- No limit on input rise and fall time
- Standard B-series output drive
- Hysteresis voltage (any input) T<sub>A</sub> = 25°C

$$\begin{split} \text{Typical} & \quad \text{$V_{DD}=5.0$V} \quad \text{$V_{H}=1.5$V} \\ & \quad \text{$V_{DD}=10$V} \quad \text{$V_{H}=2.2$V} \\ & \quad \text{$V_{DD}=15$V} \quad \text{$V_{H}=2.7$V} \\ \text{Guaranteed} & \quad \text{$V_{H}=0.1$ $V_{DD}$} \end{split}$$

## **Applications**

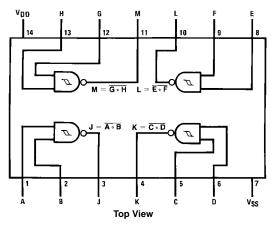
- · Wave and pulse shapers
- · High-noise-environment systems
- Monostable multivibrators
- Astable multivibrators
- NAND logic

## **Ordering Code:**

Order Number	Package Number	Package Description
CD4093BCM	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
CD4093BCN	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

#### **Connection Diagram**



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## **Absolute Maximum Ratings**(Note 1)

(Note 2)

**Recommended Operating** Conditions (Note 2) DC Supply Voltage (V<sub>DD</sub>)

DC Supply Voltage  $(V_{DD})$ -0.5 to +18  $V_{DC}$ Input Voltage (V<sub>IN</sub>) -0.5 to  $V_{DD}$  +0.5  $V_{DC}$ Storage Temperature Range  $(T_S)$ 

Input Voltage (V<sub>IN</sub>) -65°C to +150°C Operating Temperature Range (T<sub>A</sub>)

3 to 15  $\mathrm{V}_{\mathrm{DC}}$ 0 to  $V_{DD} V_{DC}$ 

Power Dissipation (P<sub>D</sub>)

700 mW

 $-55^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$ Note 1: "Absolute Maximum Ratings" are those values beyond which the

Small Outline

500 mW

safety of the device cannot be guaranteed; they are not meant to imply that the devices should be operated at these limits. The table of "Recommended Operating Conditions" and "Electrical Characteristics" provides conditions for actual device operation.

Lead Temperature (T<sub>L</sub>)

Dual-In-Line

Note 2:  $V_{SS} = 0V$  unless otherwise specified.

(Soldering, 10 seconds)

260°C

## DC Electrical Characteristics (Note 2)

Symbol	Parameter	Conditions	-55	-55°C		+25°C			+125°C	
	Parameter		Min	Max	Min	Тур	Max	Min	Max	Units
I <sub>DD</sub>	Quiescent Device	$V_{DD} = 5V$		0.25			0.25		7.5	
	Current	$V_{DD} = 10V$		0.5			0.5		15.0	μΑ
		$V_{DD} = 15V$		1.0			1.0		30.0	
V <sub>OL</sub>	LOW Level	$V_{IN} = V_{DD}$ , $ I_O  < 1 \mu A$								
	Output Voltage	$V_{DD} = 5V$		0.05		0	0.05		0.05	
		$V_{DD} = 10V$		0.05		0	0.05		0.05	V
		$V_{DD} = 15V$		0.05		0	0.05		0.05	
V <sub>OH</sub>	HIGH Level	$V_{IN} = V_{SS},  I_O  < 1 \mu A$								
	Output Voltage	$V_{DD} = 5V$	4.95		4.95	5		4.95		
		$V_{DD} = 10V$	9.95		9.95	10		9.95		V
		$V_{DD} = 15V$	14.95		14.95	15		14.95		
V <sub>T</sub> -	Negative-Going Threshold	I <sub>O</sub>   < 1 μA								
	Voltage (Any Input)	$V_{DD} = 5V, V_{O} = 4.5V$	1.3	2.25	1.5	1.8	2.25	1.5	2.3	
		$V_{DD} = 10V, V_{O} = 9V$	2.85	4.5	3.0	4.1	4.5	3.0	4.65	V
		$V_{DD} = 15V, V_{O} = 13.5V$	4.35	6.75	4.5	6.3	6.75	4.5	6.9	
V <sub>T</sub> +	Positive-Going Threshold	I <sub>O</sub>   < 1 μA								
	Voltage (Any Input)	$V_{DD} = 5V, V_{O} = 0.5V$	2.75	3.6	2.75	3.3	3.5	2.65	3.5	
		$V_{DD} = 10V, V_{O} = 1V$	5.5	7.15	5.5	6.2	7.0	5.35	7.0	V
		$V_{DD} = 15V, V_{O} = 1.5V$	8.25	10.65	8.25	9.0	10.5	8.1	10.5	
V <sub>H</sub>	Hysteresis (V <sub>T</sub> + – V <sub>T</sub> –)	$V_{DD} = 5V$	0.5	2.35	0.5	1.5	2.0	0.35	2.0	
	(Any Input)	$V_{DD} = 10V$	1.0	4.3	1.0	2.2	4.0	0.70	4.0	V
		$V_{DD} = 15V$	1.5	6.3	1.5	2.7	6.0	1.20	6.0	
l <sub>OL</sub>	LOW Level Output	$V_{IN} = V_{DD}$								
	Current (Note 3)	$V_{DD} = 5V, V_{O} = 0.4V$	0.64		0.51	0.88		0.36		
		$V_{DD} = 10V, V_{O} = 0.5V$	1.6		1.3	2.25		0.9		mA
		$V_{DD} = 15V, V_{O} = 1.5V$	4.2		3.4	8.8		2.4		
l <sub>OH</sub>	HIGH Level Output	$V_{IN} = V_{SS}$								
	Current (Note 3)	$V_{DD} = 5V, V_{O} = 4.6V$	-0.64		0.51	-0.88		-0.36		
		$V_{DD} = 10V, V_{O} = 9.5V$	-1.6		-1.3	-2.25		-0.9		mA
		$V_{DD} = 15V, V_{O} = 13.5V$	-4.2		-3.4	-8.8		-2.4		
I <sub>IN</sub>	Input Current	V <sub>DD</sub> = 15V, V <sub>IN</sub> = 0V		-0.1		-10 <sup>-5</sup>	-0.1		-1.0	
		$V_{DD} = 15V, V_{IN} = 15V$		0.1		10 <sup>-5</sup>	0.1		1.0	μΑ
	1							1		1

Note 3: I<sub>OH</sub> and I<sub>OL</sub> are tested one output at a time.

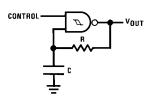
# AC Electrical Characteristics (Note 4) $T_A=25^{\circ}C,\ C_L=50\ \text{pF},\ R_L=200\text{k},\ \text{Input}\ t_f,\ t_f=20\ \text{ns},\ \text{unless otherwise specified}$

Symbol	Parameter	Conditions	Min	Тур	Max	Units
t <sub>PHL</sub> , t <sub>PLH</sub>	Propagation Delay Time	$V_{DD} = 5V$		300	450	
		$V_{DD} = 5V$ $V_{DD} = 10V$ $V_{DD} = 15V$		120	210	ns
				80	160	
t <sub>THL</sub> , t <sub>TLH</sub>	Transition Time	$V_{DD} = 5V$ $V_{DD} = 10V$ $V_{DD} = 15V$		90	145	
		$V_{DD} = 10V$		50	75	ns
		$V_{DD} = 15V$		40	60	
C <sub>IN</sub>	Input Capacitance	(Any Input)		5.0	7.5	pF
C <sub>PD</sub>	Power Dissipation Capacitance	(Per Gate)		24		pF

Note 4: AC Parameters are guaranteed by DC correlated testing.

# **Typical Applications**

## **Gated Oscillator**



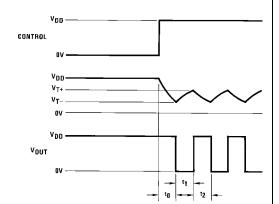
Assume  $t_1 + t_2 >> t_{PHL} + t_{PLH}$  then:

 $t_0 = RC \ \textit{In} \ [V_{DD}/V_{T}-]$ 

 $t_1 = RC \ \textit{In} \ [(V_{DD} - V_{T}\!\!-\!\!)/(V_{DD} - V_{T}\!\!+\!\!)]$ 

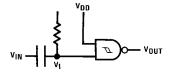
 $t_2 = RC \ln [V_T^{+/V}T^{-]}$ 

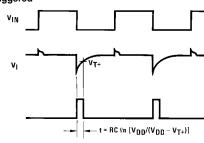
$$f = \frac{1}{t_1 + t_2} = \frac{1}{RC \, \ln \frac{(V_T^+) (V_{DD} - V_T^-)}{(V_T^-)(V_{DD} - V_T^+)}}$$

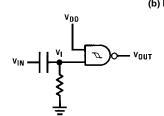


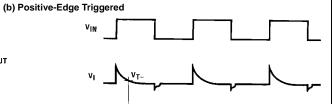
#### **Gated One-Shot**

#### (a) Negative-Edge Triggered







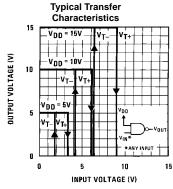


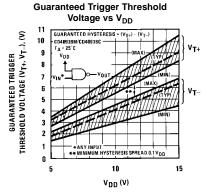
- t = RC (n (V<sub>DD</sub>/V<sub>T</sub>\_)

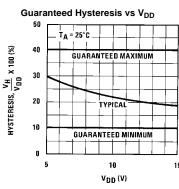
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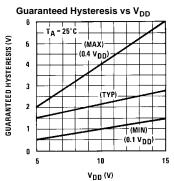
VOUT

# **Typical Performance Characteristics**

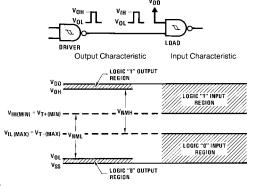






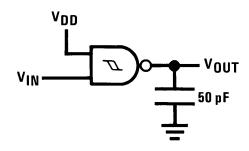


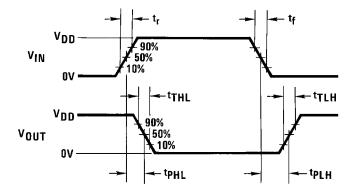
# **Input and Output Characteristics**

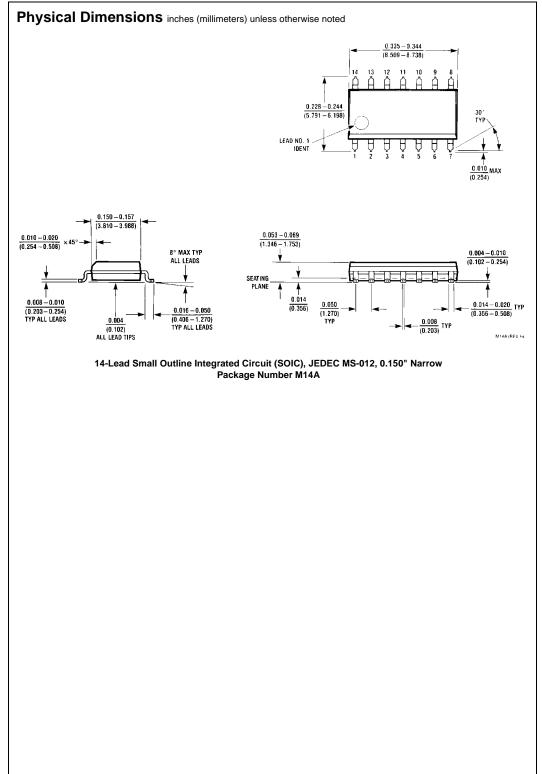


$$\begin{split} V_{NML} &= V_{IH(MIN)} - V_{OL} \cong V_{IH(MIN)} = V_{T}+_{(MIN)} \\ V_{NMH} &= V_{OH} - V_{IL(MAX)} \cong V_{DD} - V_{IL(MAX)} = V_{DD} - V_{T}-_{(MAX)} \end{split}$$

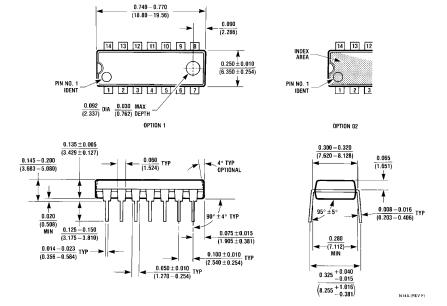
# **AC Test Circuits and Switching Time Waveforms**







#### Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide Package Number N14A

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